

High Precision Operational Amplifiers

1 Features

- Ultralow Offset Voltage: 10 μ V
- Ultralow Drift: $\pm 0.1 \mu$ V/ $^{\circ}$ C
- High Open-Loop Gain: 134 dB
- High Common-Mode Rejection: 140 dB
- High Power Supply Rejection: 130 dB
- Low Bias Current: 1-nA maximum
- Wide Supply Range: ± 2 V to ± 18 V
- Low Quiescent Current: 800 μ A/amplifier
- Single, Dual, and Quad Versions

2 Applications

- Transducer Amplifiers
- Bridge Amplifiers
- Temperature Measurements
- Strain Gage Amplifiers
- Precision Integrators
- Battery-Powered Instruments
- Test Equipment

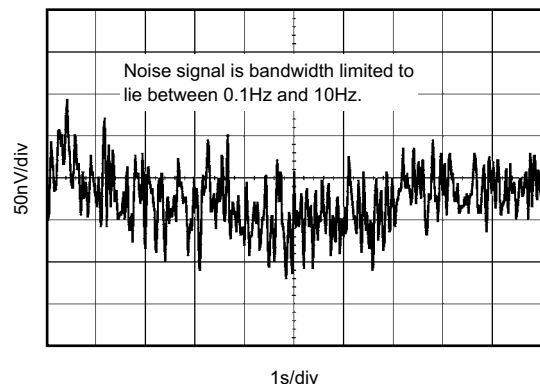
3 Description

The OPAx277 series precision operational amplifiers replace the industry standard OPA177. They offer improved noise, wider output voltage swing, and are twice as fast with half the quiescent current. Features include ultralow offset voltage and drift, low bias current, high common-mode rejection, and high power supply rejection. Single, dual, and quad versions have identical specifications, for maximum design flexibility.

OPAx277 series operational amplifiers operate from ± 2 -V to ± 18 -V supplies with excellent performance. Unlike most operational amplifiers which are specified at only one supply voltage, the OPAx277 series is specified for real-world applications; a single limit applies over the ± 5 -V to ± 15 -V supply range. High performance is maintained as the amplifiers swing to their specified limits. Because the initial offset voltage ($\pm 20 \mu$ V maximum) is so low, user adjustment is usually not required. However, the single version (OPA277) provides external trim pins for special applications.

OPA277 operational amplifiers are easy to use and free from phase inversion and the overload problems found in some other operational amplifiers. They are stable in unity gain and provide excellent dynamic behavior over a wide range of load conditions. Dual and quad versions feature completely independent circuitry for lowest crosstalk and freedom from interaction, even when overdriven or overloaded.

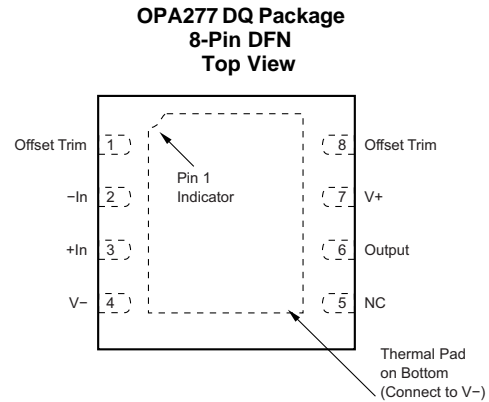
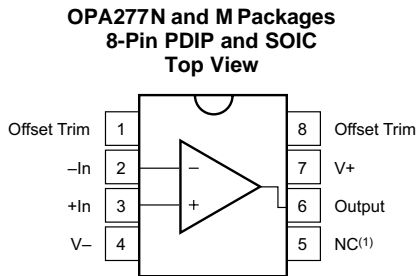
0.1 Hz to 10 Hz Noise



ORDERING INFORMATION

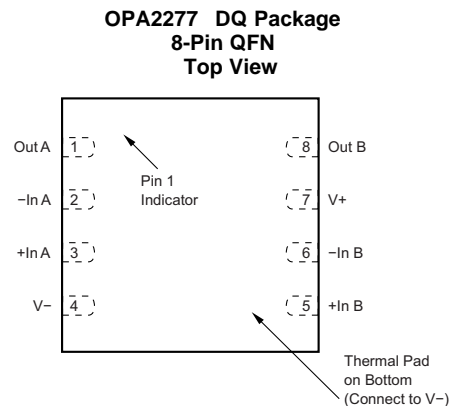
| DEVICE | Package Type | MARKING | Packing | Packing Qty |
|---------------|--------------|----------|---------|--------------|
| OPA277UN | DIP8L | A277U | TUBE | 2000pcs/box |
| OPA2277UN | DIP8L | A2277U | TUBE | 2000pcs/box |
| OPA4277UN | DIP14L | OPA4277U | TUBE | 1000pcs/box |
| OPA277UM/TR | SOP8L | A277U | REEL | 2500pcs/reel |
| OPA2277UM/TR | SOP8L | A2277U | REEL | 2500pcs/reel |
| OPA277UAM/TR | SOP8L | A277UA | REEL | 2500pcs/reel |
| OPA2277UAM/TR | SOP8L | A2277UA | REEL | 2500pcs/reel |
| OPA4277UM/TR | SOP14L | OPA4277U | REEL | 2500pcs/reel |
| OPA277UDQ/TR | DFN-8 | A277U | REEL | 3000pcs/reel |
| OPA2277UDQ/TR | DFN-8 | A2277U | REEL | 3000pcs/reel |

4 Pin Configuration and Functions



Pin Functions: OPA277

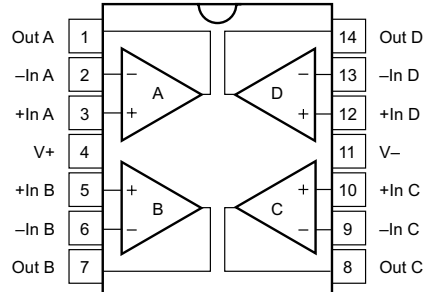
| PIN | | I/O | DESCRIPTION |
|-----|-------------|-----|--|
| NO. | NAME | | |
| 1 | Offset Trim | I | Input offset voltage trim (leave floating if not used) |
| 2 | -In | I | Inverting input |
| 3 | +In | I | Noninverting input |
| 4 | V- | — | Negative (lowest) power supply |
| 5 | NC | — | No internal connection (can be left floating) |
| 6 | Output | O | Output |
| 7 | V+ | — | Positive (highest) power supply |
| 8 | Offset Trim | — | Input offset voltage trim (leave floating if not used) |



Pin Functions: OPA2277

| PIN | | | I/O | DESCRIPTION |
|-------|----------------|---------|-----|---------------------------------|
| NAME | PDIP, SOIC NO. | DFN NO. | | |
| Out A | 1 | 1 | O | Output channel A |
| -In A | 2 | 2 | I | Inverting input channel A |
| +In A | 3 | 3 | I | Noninverting input channel A |
| V- | 4 | 4 | — | Negative (lowest) power supply |
| +In B | 5 | 5 | I | Noninverting input channel B |
| -In B | 6 | 6 | I | Inverting input channel B |
| Out B | 7 | 8 | O | Output channel B |
| V+ | 8 | 7 | — | Positive (highest) power supply |

**OPA4277N and M Packages
14 Pins PDIP and SOIC
Top View**



Pin Functions: OPA4277

| PIN | | I/O | DESCRIPTION |
|-----|-------|-----|---------------------------------|
| NO. | NAME | | |
| 1 | Out A | O | Output channel A |
| 2 | -In A | I | Inverting input channel A |
| 3 | +In A | I | Noninverting input channel A |
| 4 | V+ | — | Positive (highest) power supply |
| 5 | +In B | I | Noninverting input channel B |
| 6 | -In B | I | Inverting input channel B |
| 7 | Out B | O | Output channel B |
| 8 | Out C | O | Output channel C |
| 9 | -In C | I | Inverting input channel C |
| 10 | +In C | I | Noninverting input channel C |
| 11 | V- | — | Negative (lowest) power supply |
| 12 | +In D | I | Noninverting input channel D |
| 13 | -In D | I | Inverting input channel D |
| 14 | Out D | O | Output channel D |

5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) ⁽¹⁾

| | MIN | MAX | UNIT |
|-------------------------------------|------------|-----------|------|
| Supply voltage, $V_s = (V+) - (V-)$ | | 36 | V |
| Input voltage | (V-) -0.7 | (V+) +0.7 | V |
| Output short-circuit ⁽²⁾ | Continuous | | |
| Operating temperature | -20 | 85 | °C |
| Junction temperature | | 150 | °C |
| Lead temperature | | 300 | °C |
| Storage temperature, T_{stg} | -20 | 125 | °C |

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) Short-circuit to ground, one amplifier per package.

5.2 ESD Ratings

| | | VALUE | UNIT |
|-------------------------------------|--|-------|------|
| $V_{(ESD)}$ Electrostatic discharge | Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾ | ±2000 | V |
| | Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾ | ±500 | |

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

5.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

| | MIN | NOM | MAX | UNIT |
|-------------------------------------|--------|----------|----------|------|
| Supply voltage, $V_s = (V+) - (V-)$ | 4 (±2) | 30 (±15) | 36 (±18) | V |
| Specified temperature | -20 | | +85 | °C |

5.4 Thermal Information for OPA277

| THERMAL METRIC ⁽¹⁾ | OPA277 | | | UNIT |
|---|----------|----------|----------|------|
| | N (PDIP) | M (SOIC) | DQ (QFN) | |
| | 8 PINS | | | |
| $R_{\theta JA}$ Junction-to-ambient thermal resistance | 49.2 | 110.1 | 40.7 | °C/W |
| $R_{\theta JC(top)}$ Junction-to-case (top) thermal resistance | 39.4 | 52.2 | 41.3 | °C/W |
| $R_{\theta JB}$ Junction-to-board thermal resistance | 26.4 | 52.3 | 16.7 | °C/W |
| Ψ_{JT} Junction-to-top characterization parameter | 15.4 | 10.4 | 0.6 | °C/W |
| Ψ_{JB} Junction-to-board characterization parameter | 26.3 | 51.5 | 16.9 | °C/W |
| $R_{\theta JC(bot)}$ Junction-to-case (bottom) thermal resistance | — | — | 3.3 | °C/W |

- (1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report, [SPRA953](#).

5.5 Thermal Information for OPA2277

| THERMAL METRIC ⁽¹⁾ | OPA2277 | | | UNIT |
|--|----------|----------|----------|------|
| | N (PDIP) | M (SOIC) | DQ (DFN) | |
| | 8 PINS | | | |
| $R_{\theta JA}$ Junction-to-ambient thermal resistance | 47.2 | 107.4 | 39.3 | °C/W |
| $R_{\theta JC(top)}$ Junction-to-case (top) thermal resistance | 36.0 | 45.8 | 36.9 | °C/W |

- (1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report, [SPRA953](#).

Thermal Information for OPA2277(continued)

| THERMAL METRIC ⁽¹⁾ | | OPA2277 | | | UNIT |
|-------------------------------|--|----------|----------|----------|------|
| | | N (PDIP) | M (SOIC) | DQ (DFN) | |
| | | 8 PINS | | | |
| R _{θJB} | Junction-to-board thermal resistance | 24.4 | 47.9 | 15.4 | °C/W |
| ψ _{JT} | Junction-to-top characterization parameter | 13.4 | 5.7 | 0.4 | °C/W |
| ψ _{JB} | Junction-to-board characterization parameter | 24.3 | 47.3 | 15.6 | °C/W |
| R _{θJC(bot)} | Junction-to-case (bottom) thermal resistance | — | — | 2.2 | °C/W |

5.6 Thermal Information for OPA4277

| THERMAL METRIC ⁽¹⁾ | | OPA4277 | | UNIT |
|-------------------------------|--|----------|----------|------|
| | | N (SOIC) | M (PDIP) | |
| | | 14 PINS | | |
| R _{θJA} | Junction-to-ambient thermal resistance | 67.0 | 66.3 | °C/W |
| R _{θJC(top)} | Junction-to-case (top) thermal resistance | 24.1 | 20.5 | °C/W |
| R _{θJB} | Junction-to-board thermal resistance | 22.5 | 26.8 | °C/W |
| ψ _{JT} | Junction-to-top characterization parameter | 2.2 | 2.1 | °C/W |
| ψ _{JB} | Junction-to-board characterization parameter | 22.1 | 26.2 | °C/W |
| R _{θJC(bot)} | Junction-to-case (bottom) thermal resistance | — | — | °C/W |

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report, [SPRA953](#).

5.7 Electrical Characteristics for OPAx277U, and OPAx277UA

At T_A = 25°C, and R_L = 2 kΩ, unless otherwise noted

| PARAMETER | | TEST CONDITIONS | OPA277U OPA2277U | | | OPA277UA OPA2277UA OPA4277UA | | | UNIT |
|-----------------------|---------------------------------------|------------------------------|--|--------------------|-------|------------------------------------|--------------------|-----|-------|
| | | | MIN | TYP ⁽¹⁾ | MAX | MIN | TYP ⁽¹⁾ | MAX | |
| OFFSET VOLTAGE | | | | | | | | | |
| V _{OS} | Input Offset Voltage | | | ±10 | ±20 | | ±20 | ±50 | μV |
| | Input Offset Voltage Over Temperature | OPA277U (high-grade, single) | T _A = -20°C to 85°C | | ±30 | | | | μV |
| | | OPA2277U (high-grade, dual) | | | ±50 | | | | |
| | | All Versions | | | | | ±100 | | |
| | | AIDRM Versions | | | | | | | |
| dV _{OS} /dT | Input Offset Voltage Drift | OPA277U (high-grade, single) | T _A = -20°C to 85°C | ±0.1 | ±0.15 | | | | μV/°C |
| | | OPA2277U (high-grade, dual) | | ±0.1 | ±0.25 | | | | |
| | | All AIDRM Versions | | | | ±0.15 | ±1 | | |
| | Input Offset Voltage: (all models) | vs Time | | 0.2 | | | See ⁽²⁾ | | μV/mo |
| | | vs Power Supply (PSRR) | V _S = ±2 V to ±18 V T _A = -20°C to 85°C | ±0.3 | ±0.5 | | See ⁽²⁾ | ±1 | μV/V |
| | Channel Separation (dual, quad) | DC | | 0.1 | | | See ⁽²⁾ | | μV/V |

(1) V_S = ±15 V

(2) Specifications are the same as OPA277U

Electrical Characteristics for OPAx277U, and OPAx277UA(continued)

At $T_A = 25^\circ\text{C}$, and $R_L = 2\text{ k}\Omega$, unless otherwise noted

| PARAMETER | | TEST CONDITIONS | OPA277U OPA2277U | | | OPA277UA OPA2277UA OPA4277UA | | | UNIT |
|----------------------------|--|--|---|---------------------|-----------|------------------------------------|--------------------|--------------------|------------------------|
| | | | MIN | TYP ⁽¹⁾ | MAX | MIN | TYP ⁽¹⁾ | MAX | |
| INPUT BIAS CURRENT | | | | | | | | | |
| I_B | Input Bias Current | $T_A = -20^\circ\text{C}$ to 85°C | | ± 0.5 | ± 1 | | See ⁽²⁾ | ± 2.8 | nA |
| | | | | | | | | ± 4 | |
| I_{OS} | Input Offset Current | $T_A = -20^\circ\text{C}$ to 85°C | | ± 0.5 | ± 1 | | See ⁽²⁾ | ± 2.8 | nA |
| | | | | | | | | ± 4 | |
| NOISE | | | | | | | | | |
| | Input Voltage Noise, $f = 0.1$ to 10 Hz | | | 0.22 | | | See ⁽²⁾ | | μV_{PP} |
| e_n | Input Voltage Noise Density | | | $f = 10\text{ Hz}$ | | | See ⁽²⁾ | | nV/ $\sqrt{\text{Hz}}$ |
| | | | | $f = 100\text{ Hz}$ | 12 | | See ⁽²⁾ | | |
| | | | | $f = 1\text{ kHz}$ | 8 | | See ⁽²⁾ | | |
| | | | | $f = 10\text{ kHz}$ | 8 | | See ⁽²⁾ | | |
| i_n | Current Noise Density, $f = 1\text{ kHz}$ | | | 0.2 | | | See ⁽²⁾ | | pA/ $\sqrt{\text{Hz}}$ |
| INPUT VOLTAGE RANGE | | | | | | | | | |
| V_{CM} | Common-Mode Voltage Range | | | $(V_-)+2$ | $(V_+)-2$ | | See ⁽²⁾ | See ⁽²⁾ | V |
| CMRR | Common-Mode Rejection | $V_{CM} = (V_-)+2\text{ V}$ to $(V_+)-2\text{ V}$ | | 130 | 140 | | 115 | See ⁽²⁾ | dB |
| | | $T_A = -20^\circ\text{C}$ to 85°C | | 128 | | | 115 | | |
| INPUT IMPEDANCE | | | | | | | | | |
| | Differential | | | 100 3 | | | See ⁽²⁾ | | M Ω pF |
| | Common-Mode | $V_{CM} = (V_-)+2\text{ V}$ to $(V_+)-2\text{ V}$ | | 250 3 | | | See ⁽²⁾ | | G Ω pF |
| OPEN-LOOP GAIN | | | | | | | | | |
| A_{OL} | Open-Loop Voltage Gain | $V_O = (V_-)+0.5\text{ V}$ to $(V_+)-1.2\text{ V}$, $R_L = 10\text{ k}\Omega$ | | 140 | | | See ⁽²⁾ | | dB |
| | | $V_O = (V_-)+1.5\text{ V}$ to $(V_+)-1.5\text{ V}$, $R_L = 2\text{ k}\Omega$ | | 126 | 134 | | See ⁽²⁾ | See ⁽²⁾ | |
| | | $V_O = (V_-)+1.5\text{ V}$ to $(V_+)-1.5\text{ V}$, $R_L = 2\text{ k}\Omega$ | | 126 | | | See ⁽²⁾ | | dB |
| | | $T_A = -20^\circ\text{C}$ to 85°C | | | | | | | |
| FREQUENCY RESPONSE | | | | | | | | | |
| GBW | Gain-Bandwidth Product | | | 1 | | | See ⁽²⁾ | | MHz |
| SR | Slew Rate | | | 0.8 | | | See ⁽²⁾ | | V/ μs |
| | Settling Time | 0.1% | $V_S = \pm 15\text{ V}$, $G = 1$, 10-V Step | 14 | | | See ⁽²⁾ | | μs |
| | | 0.01% | | 16 | | See ⁽²⁾ | | | |
| | Overload Recovery Time | $V_{IN} \times G = V_S$ | | 3 | | | See ⁽²⁾ | | μs |
| THD+N | Total Harmonic Distortion + Noise | 1 kHz, $G = 1$, $V_O = 3.5\text{ V}_{rms}$ | | 0.002% | | | See ⁽²⁾ | | |

Electrical Characteristics for OPAx277U, and OPAx277UA (continued)

At $T_A = 25^\circ\text{C}$, and $R_L = 2\text{ k}\Omega$, unless otherwise noted

| PARAMETER | TEST CONDITIONS | OPA277N,M OPA2277N,M | | | OPA277x OPA2277x OPA4277x | | | UNIT |
|--------------------------|-----------------------------------|--|--------------------|-----------|---------------------------------|--------------------|------------------|--------------------|
| | | MIN | TYP ⁽¹⁾ | MAX | MIN | TYP ⁽¹⁾ | MAX | |
| OUTPUT | | | | | | | | |
| V_O | Voltage Output | $R_L = 10\text{ k}\Omega$ | (V-) +0.5 | (V+) -1.2 | See ⁽²⁾ | See ⁽²⁾ | V | |
| | | $T_A = -20^\circ\text{C}$ to $+85^\circ\text{C}$ | (V-) +0.5 | (V+) -1.2 | See ⁽²⁾ | See ⁽²⁾ | | |
| | | $R_L = 2\text{ k}\Omega$ | (V-) +1.5 | (V+) -1.5 | See ⁽²⁾ | See ⁽²⁾ | | |
| | | $T_A = -20^\circ\text{C}$ to $+85^\circ\text{C}$ | (V-) +1.5 | (V+) -1.5 | See ⁽²⁾ | See ⁽²⁾ | | |
| I_{SC} | Short-Circuit Current | | ± 35 | | See ⁽²⁾ | | mA | |
| C_{LOAD} | Capacitive Load Drive | | See ⁽³⁾ | | | | | |
| Z_O | Open-loop output impedance | $f = 1\text{ MHz}$ | 40 | | See ⁽²⁾ | | Ω | |
| POWER SUPPLY | | | | | | | | |
| V_S | Specified Voltage Range | | ± 5 | ± 15 | See ⁽²⁾ | See ⁽²⁾ | V | |
| | Operating Voltage Range | | ± 2 | ± 18 | See ⁽²⁾ | See ⁽²⁾ | V | |
| I_Q | Quiescent Current (per amplifier) | $I_O = 0$ | ± 790 | ± 825 | See ⁽²⁾ | See ⁽²⁾ | μA | |
| | | $T_A = -20^\circ\text{C}$ to 85°C | | ± 900 | | See ⁽²⁾ | | See ⁽²⁾ |
| TEMPERATURE RANGE | | | | | | | | |
| | Specified Range | | -20 | 85 | See ⁽²⁾ | See ⁽²⁾ | $^\circ\text{C}$ | |
| | Operating Range | | -20 | 125 | See ⁽²⁾ | See ⁽²⁾ | $^\circ\text{C}$ | |

(3) See *Typical Characteristics*

6.8 Electrical Characteristics for OPAx277UDQ

At $T_A = 25^\circ\text{C}$, and $R_L = 2\text{ k}\Omega$, unless otherwise noted

| PARAMETER | TEST CONDITIONS | OPA277UDQ OPA2277UDQ | | | UNIT | |
|-----------------------|---------------------------------------|------------------------------|---|--------------------|------------------------------|------------------------|
| | | MIN | TYP ⁽¹⁾ | MAX | | |
| OFFSET VOLTAGE | | | | | | |
| V_{OS} | Input Offset Voltage | | ± 35 | ± 100 | μV | |
| | Input Offset Voltage Over Temperature | OPA277U (high-grade, single) | $T_A = -20^\circ\text{C}$ to 85°C | | μV | |
| | | OPA2277U (high-grade, dual) | | | | |
| | | All Versions | | | | |
| | | AIDRM Versions | | | | ± 165 |
| dV_{OS}/dT | Input Offset Voltage Drift | OPA277U (high-grade, single) | $T_A = -20^\circ\text{C}$ to 85°C | | $\mu\text{V}/^\circ\text{C}$ | |
| | | OPA2277U (high-grade, dual) | | | | |
| | | All Versions | | | | ± 0.15 |
| | Input Offset Voltage: (all models) | vs Time | | See ⁽²⁾ | $\mu\text{V}/\text{mo}$ | |
| | | vs Power Supply (PSRR) | $V_S = \pm 2\text{ V}$ to $\pm 18\text{ V}$ | See ⁽²⁾ | ± 1 | $\mu\text{V}/\text{V}$ |
| | | | $T_A = -20^\circ\text{C}$ to 85°C | | ± 1 | |
| | Channel Separation (dual, quad) | DC | | See ⁽²⁾ | $\mu\text{V}/\text{V}$ | |

(1) $V_S = \pm 15\text{ V}$

(2) Specifications are the same as OPA277U

Electrical Characteristics for OPAx277UDQ(continued)

At $T_A = 25^\circ\text{C}$, and $R_L = 2\text{ k}\Omega$, unless otherwise noted

| PARAMETER | | TEST CONDITIONS | OPA277UDQ OPA2277UDQ | | | UNIT |
|----------------------------|--|--|---|--------------------|----------------------|------------------------|
| | | | MIN | TYP ⁽¹⁾ | MAX | |
| INPUT BIAS CURRENT | | | | | | |
| I_B | Input Bias Current | $T_A = -20^\circ\text{C to } 85^\circ\text{C}$ | | | ± 2.8 ± 4 | nA |
| I_{OS} | Input Offset Current | $T_A = -20^\circ\text{C to } 85^\circ\text{C}$ | | | ± 2.8 ± 4 | nA |
| NOISE | | | | | | |
| | Input Voltage Noise, $f = 0.1$ to 10 Hz | | | See ⁽²⁾ | | μV_{PP} |
| e_n | Input Voltage Noise Density | $f = 10\text{ Hz}$ | | See ⁽²⁾ | | nV/ $\sqrt{\text{Hz}}$ |
| | | $f = 100\text{ Hz}$ | | See ⁽²⁾ | | |
| | | $f = 1\text{ kHz}$ | | See ⁽²⁾ | | |
| | | $f = 10\text{ kHz}$ | | See ⁽²⁾ | | |
| i_n | Current Noise Density, $f = 1\text{ kHz}$ | | | See ⁽²⁾ | | pA/ $\sqrt{\text{Hz}}$ |
| INPUT VOLTAGE RANGE | | | | | | |
| V_{CM} | Common-Mode Voltage Range | | | See ⁽²⁾ | See ⁽²⁾ | V |
| CMRR | Common-Mode Rejection | $V_{CM} = (V_-) + 2\text{ V to } (V_+) - 2\text{ V}$ | 115 | See ⁽²⁾ | | dB |
| | | $T_A = -20^\circ\text{C to } 85^\circ\text{C}$ | 115 | | | |
| INPUT IMPEDANCE | | | | | | |
| | Differential | | | See ⁽²⁾ | | M Ω pF |
| | Common-Mode | $V_{CM} = (V_-) + 2\text{ V to } (V_+) - 2\text{ V}$ | | See ⁽²⁾ | | G Ω pF |
| OPEN-LOOP GAIN | | | | | | |
| A_{OL} | Open-Loop Voltage Gain | $V_O = (V_-) + 0.5\text{ V to } (V_+) - 1.2\text{ V}$, $R_L = 10\text{ k}\Omega$ | | See ⁽²⁾ | | dB |
| | | $V_O = (V_-) + 1.5\text{ V to } (V_+) - 1.5\text{ V}$, $R_L = 2\text{ k}\Omega$ | See ⁽²⁾ | See ⁽²⁾ | | |
| | | $V_O = (V_-) + 1.5\text{ V to } (V_+) - 1.5\text{ V}$, $R_L = 2\text{ k}\Omega$ | | See ⁽²⁾ | | dB |
| | | $T_A = -20^\circ\text{C to } 85^\circ\text{C}$ | | | | |
| FREQUENCY RESPONSE | | | | | | |
| GBW | Gain-Bandwidth Product | | | See ⁽²⁾ | | MHz |
| SR | Slew Rate | | | See ⁽²⁾ | | V/ μs |
| | Settling Time | 0.1% | $V_S = \pm 15\text{ V}$, $G = 1$, 10-V Step | See ⁽²⁾ | | μs |
| | | 0.01% | | See ⁽²⁾ | | |
| | Overload Recovery Time | $V_{IN} \times G = V_S$ | | See ⁽²⁾ | | μs |
| THD+N | Total Harmonic Distortion + Noise | 1 kHz, $G = 1$, $V_O = 3.5\text{ V}_{rms}$ | | See ⁽²⁾ | | |
| OUTPUT | | | | | | |
| V_O | Voltage Output | $R_L = 10\text{ k}\Omega$ | | See ⁽²⁾ | See ⁽²⁾ | V |
| | | $T_A = -20^\circ\text{C to } +85^\circ\text{C}$ | | See ⁽²⁾ | See ⁽²⁾ | |
| | | $R_L = 2\text{ k}\Omega$ | | See ⁽²⁾ | See ⁽²⁾ | |
| | | $T_A = -20^\circ\text{C to } +85^\circ\text{C}$ | | See ⁽²⁾ | See ⁽²⁾ | |
| I_{SC} | Short-Circuit Current | | | See ⁽²⁾ | | mA |
| C_{LOAD} | Capacitive Load Drive | | | | | |
| Z_O | Open-loop output impedance | $f = 1\text{ MHz}$ | | See ⁽²⁾ | | Ω |

Electrical Characteristics for OPAx277UDQ (continued)

At $T_A = 25^\circ\text{C}$, and $R_L = 2\text{ k}\Omega$, unless otherwise noted

| PARAMETER | | TEST CONDITIONS | OPA277UDQ OPA2277UDQ | | | UNIT |
|--------------------------|-----------------------------------|---|-------------------------|--------------------|--------------------|------------------|
| | | | MIN | TYP ⁽¹⁾ | MAX | |
| POWER SUPPLY | | | | | | |
| V_S | Specified Voltage Range | | See ⁽²⁾ | | See ⁽²⁾ | V |
| | Operating Voltage Range | | See ⁽²⁾ | | See ⁽²⁾ | V |
| I_Q | Quiescent Current (per amplifier) | $I_O = 0$ | | See ⁽²⁾ | See ⁽²⁾ | μA |
| | | $T_A = -20^\circ\text{C}$ to 85°C | | | See ⁽²⁾ | |
| TEMPERATURE RANGE | | | | | | |
| | Specified Range | | See ⁽²⁾ | | See ⁽²⁾ | $^\circ\text{C}$ |
| | Operating Range | | See ⁽²⁾ | | See ⁽²⁾ | $^\circ\text{C}$ |

6.9 Typical Characteristics

At $T_A = 25^\circ\text{C}$, $V_S = \pm 15\text{ V}$, and $R_L = 2\text{ k}\Omega$, unless otherwise noted.

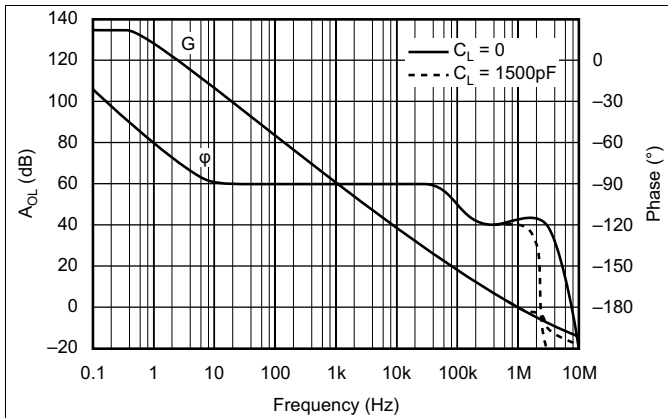


Figure 1. Open-Loop Gain and Phase vs Frequency

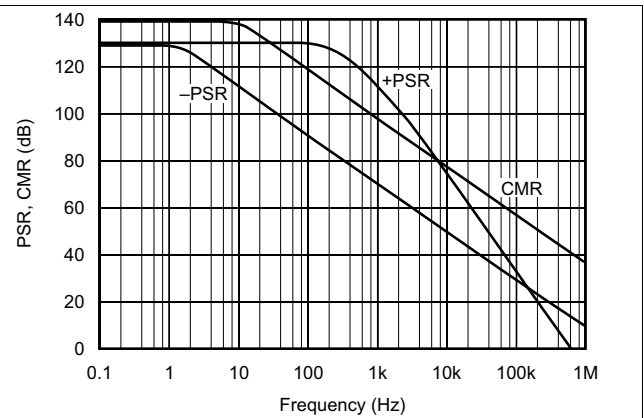


Figure 2. Power Supply and Common-Mode Rejection vs Frequency

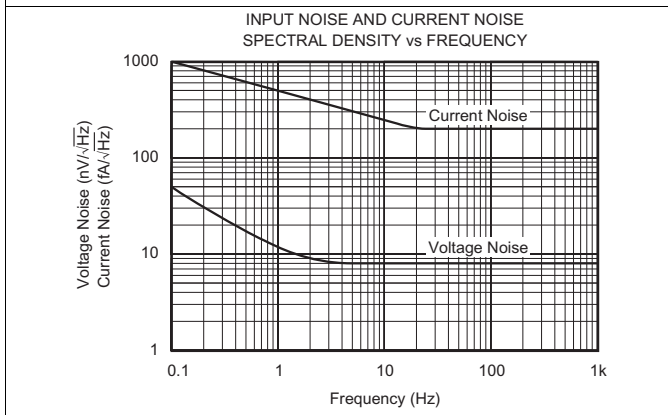


Figure 3. Input Noise and Current Noise Spectral Density vs Frequency

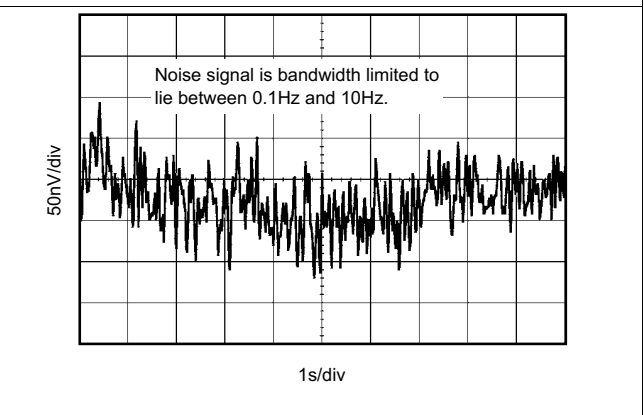


Figure 4. Input Noise Voltage vs Time

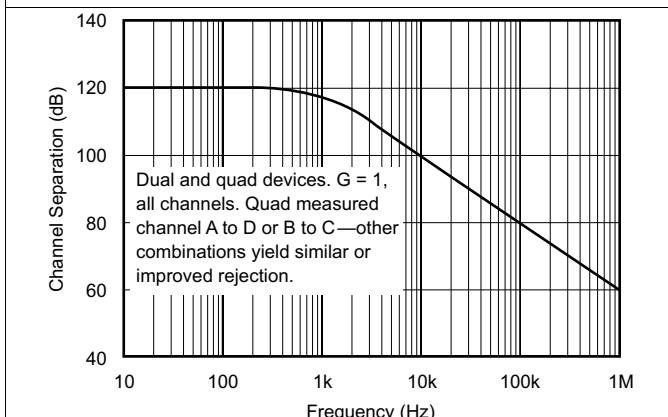


Figure 5. Channel Separation vs Frequency

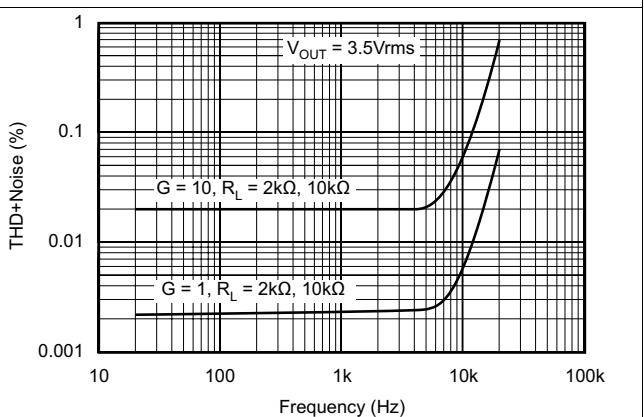


Figure 6. Total Harmonic Distortion + Noise vs Frequency

Typical Characteristics (continued)

At $T_A = 25^\circ\text{C}$, $V_S = \pm 15\text{ V}$, and $R_L = 2\text{ k}\Omega$, unless otherwise noted.

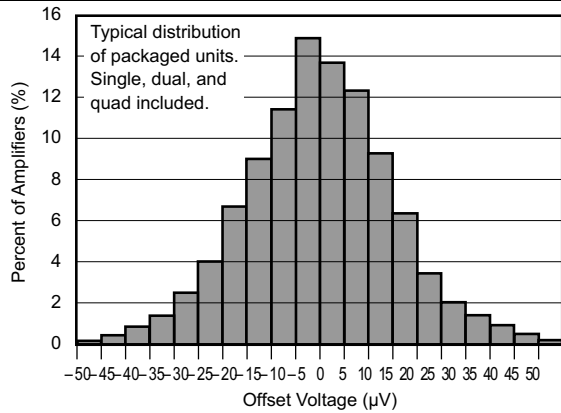


Figure 7. Offset Voltage Production Distribution

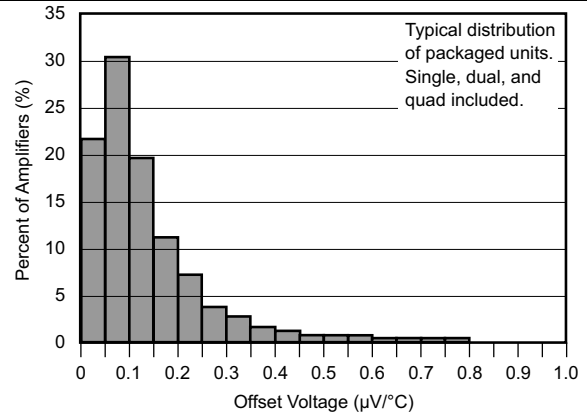


Figure 8. Offset Voltage Drift Production Distribution

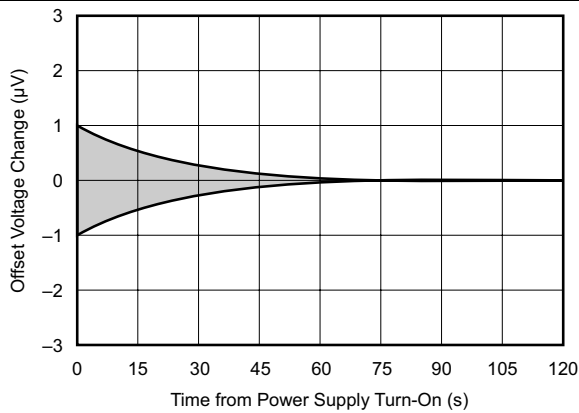


Figure 9. Warm-Up Offset Voltage Drift

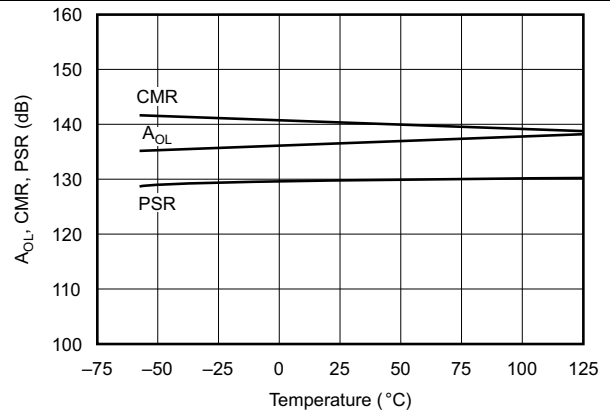


Figure 10. A_{OL} , CMR, PSR vs Temperature

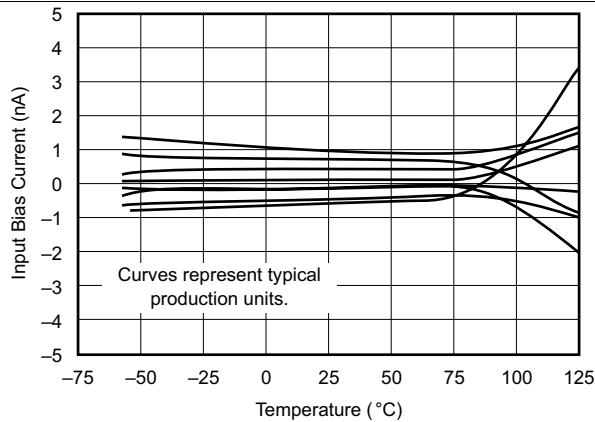


Figure 11. Input Bias Current vs Temperature

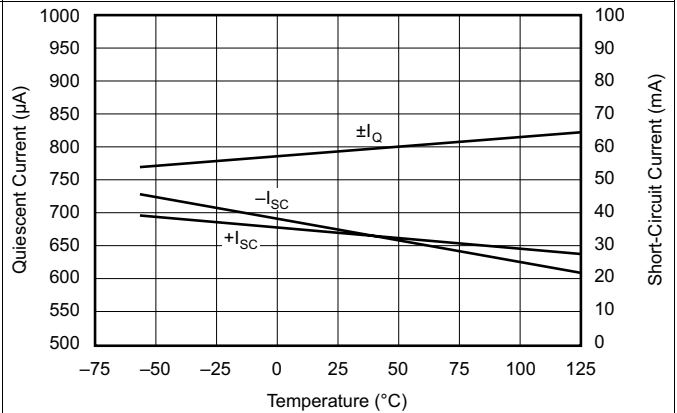


Figure 12. Quiescent Current and Short-Circuit Current vs Temperature

Typical Characteristics (continued)

At $T_A = 25^\circ\text{C}$, $V_S = \pm 15\text{ V}$, and $R_L = 2\text{ k}\Omega$, unless otherwise noted.

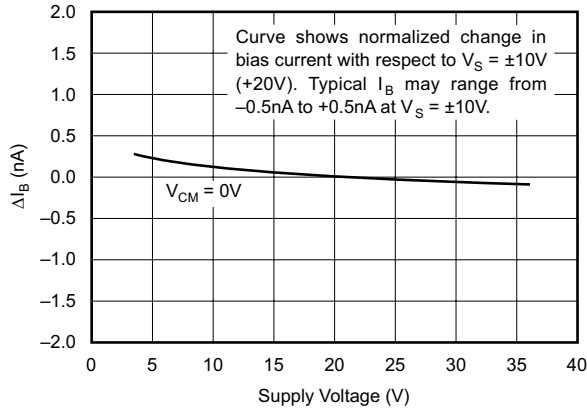


Figure 13. Change in Input Bias Current vs Power Supply Voltage

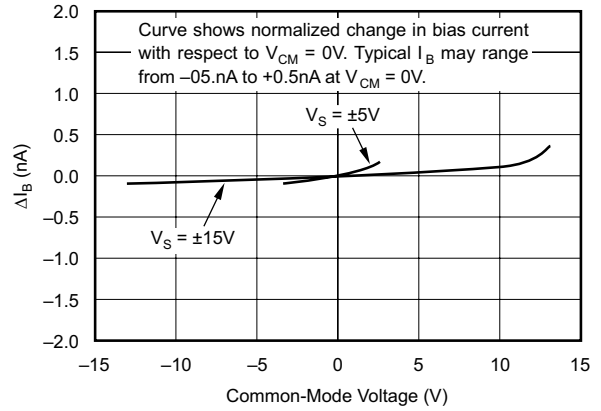


Figure 14. Change in Input Bias Current vs Common-Mode Voltage

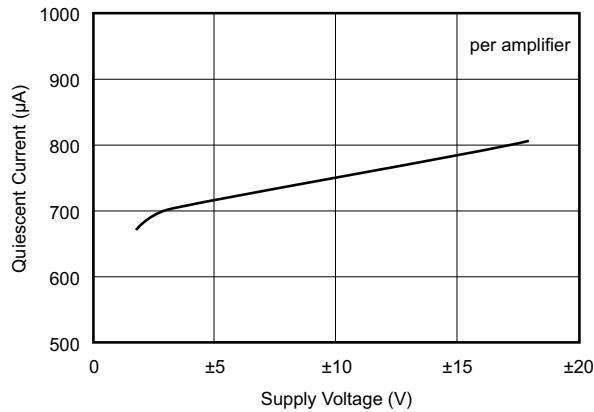


Figure 15. Quiescent Current vs Supply Voltage

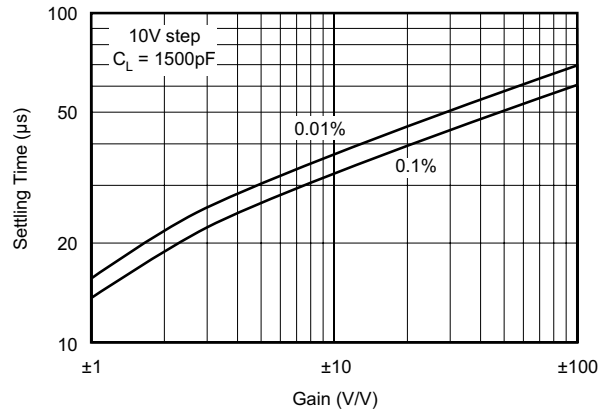


Figure 16. Settling Time vs Closed-Loop Gain

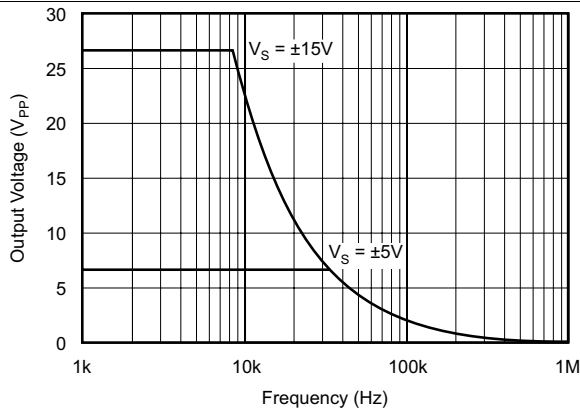


Figure 17. Maximum Output Voltage vs Frequency

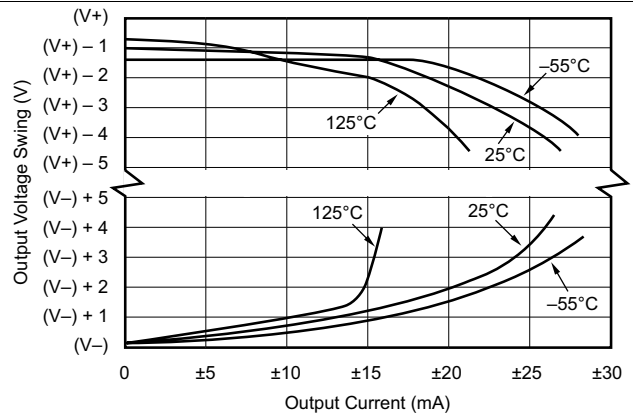


Figure 18. Output Voltage Swing vs Output Current

Typical Characteristics (continued)

At $T_A = 25^\circ\text{C}$, $V_S = \pm 15\text{ V}$, and $R_L = 2\text{ k}\Omega$, unless otherwise noted.

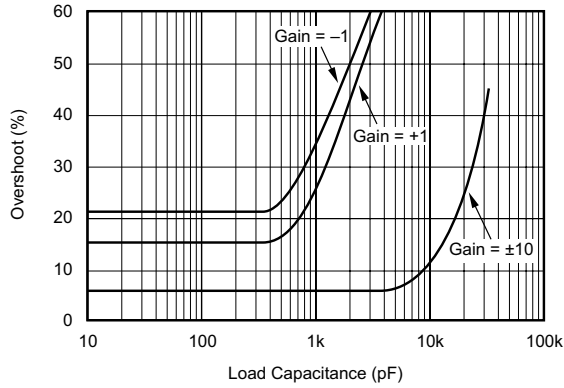


Figure 19. Small-Signal Overshoot vs Load Capacitance

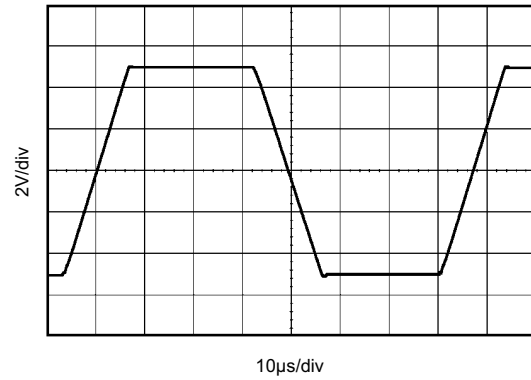


Figure 20. Large-Signal Step Response
 $G = 1$, $C_L = 1500\text{ pF}$, $V_S = \pm 15\text{ V}$

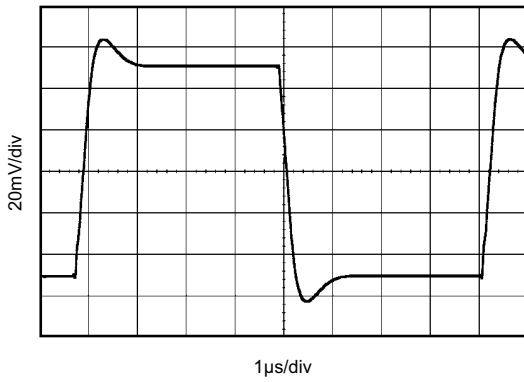


Figure 21. Small-Signal Step Response
 $G = +1$, $C_L = 0$, $V_S = \pm 15\text{ V}$

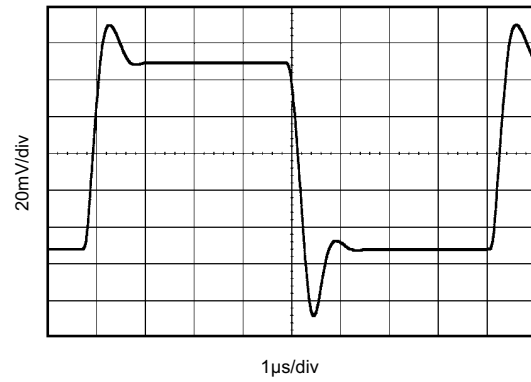


Figure 22. Small-Signal Step Response
 $G = 1$, $C_L = 1500\text{ pF}$, $V_S = \pm 15\text{ V}$

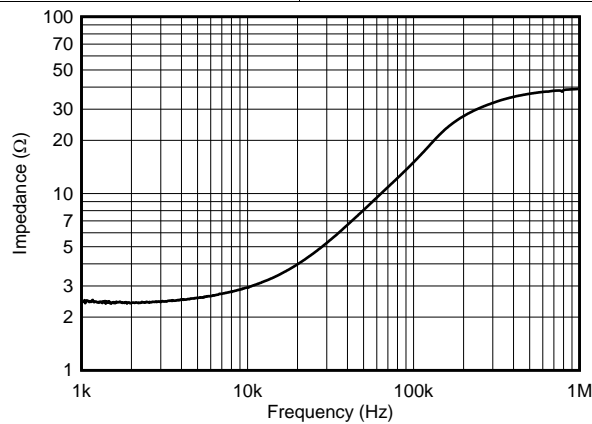


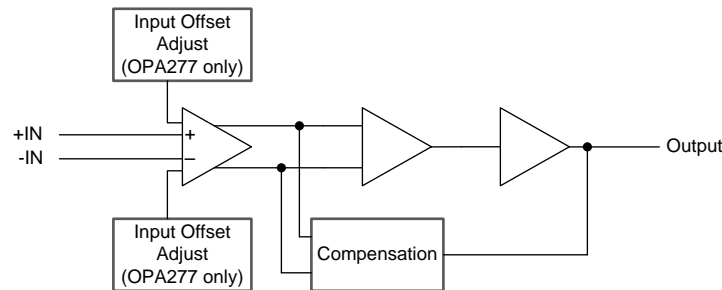
Figure 23. Open-Loop Output Impedance
 $V_S = \pm 15\text{ V}$

7 Detailed Description

7.1 Overview

The OPAx277 series precision operational amplifiers replace the industry standard OPA177. They offer improved noise, wider output voltage swing, and are twice as fast with half the quiescent current. Features include ultralow offset voltage and drift, low bias current, high common-mode rejection, and high power supply rejection. Single, dual, and quad versions have identical specifications, for maximum design flexibility.

7.2 Functional Block Diagram



7.3 Feature Description

The OPAx277 series is unity-gain stable and free from unexpected output phase reversal, making it easy to use in a wide range of applications. Applications with noisy or high-impedance power supplies may require decoupling capacitors close to the device pins. In most cases 0.1- μ F capacitors are adequate.

The OPAx277 series has low offset voltage and drift. To achieve highest performance, the circuit layout and mechanical conditions should be optimized. Offset voltage and drift can be degraded by small thermoelectric potentials at the operational amplifier inputs. Connections of dissimilar metals generate thermal potential, which can degrade the ultimate performance of the OPAx277 series. These thermal potentials can be made to cancel by assuring that they are equal in both input terminals.

- Keep the thermal mass of the connections to the two input terminals similar
- Locate heat sources as far as possible from the critical input circuitry
- Shield operational amplifier and input circuitry from air currents, such as cooling fans

7.3.1 Operating Voltage

OPAx277 series operational amplifiers operate from ± 2 -V to ± 18 -V supplies with excellent performance. Unlike most operational amplifiers, which are specified at only one supply voltage, the OPA277 series is specified for real-world applications; a single limit applies over the ± 5 -V to ± 15 -V supply range. This allows a customer operating at $V_S = \pm 10$ V to have the same assured performance as a customer using ± 15 -V supplies. In addition, key parameters are assured over the specified temperature range, -20°C to 85°C . Most behavior remains unchanged through the full operating voltage range (± 2 V to ± 18 V). Parameters which vary significantly with operating voltage or temperature are shown in [Typical Characteristics](#).

7.3.2 Offset Voltage Adjustment

The OPAx277 series is laser-trimmed for low offset voltage and drift, so most circuits do not require external adjustment. However, offset voltage trim connections are provided on pins 1 and 8. Offset voltage can be adjusted by connecting a potentiometer, as shown in [Figure 24](#). Only use this adjustment to null the offset of the operational amplifier. This adjustment should not be used to compensate for offsets created elsewhere in a system, because this can introduce additional temperature drift.

Feature Description (continued)

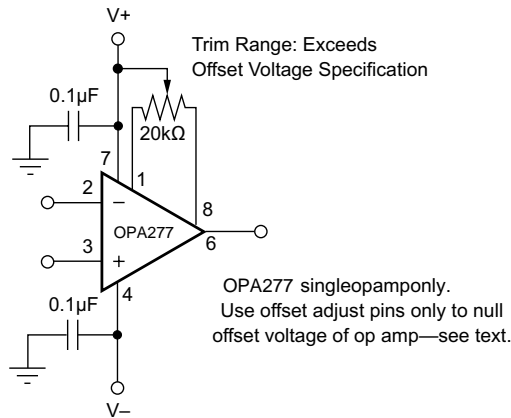


Figure 24. OPA277 Offset Voltage Trim Circuit

7.3.3 Input Protection

The inputs of the OPAx277 series are protected with 1-kΩ series input resistors and diode clamps. The inputs can withstand ±30-V differential inputs without damage. The protection diodes conduct current when the inputs are over-driven. This may disturb the slewing behavior of unity-gain follower applications, but will not damage the operational amplifier.

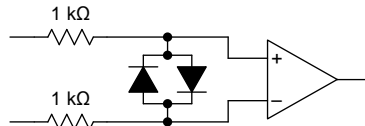


Figure 25. OPAx277 Input Protection

7.3.4 Input Bias Current Cancellation

The input stage base current of the OPAx277 series is internally compensated with an equal and opposite cancellation circuit. The resulting input bias current is the difference between the input stage base current and the cancellation current. This residual input bias current can be positive or negative.

When the bias current is canceled in this manner, the input bias current and input offset current are approximately the same magnitude. As a result, it is not necessary to use a bias current cancellation resistor, as is often done with other operational amplifiers (see Figure 26). A resistor added to cancel input bias current errors may actually increase offset voltage and noise.

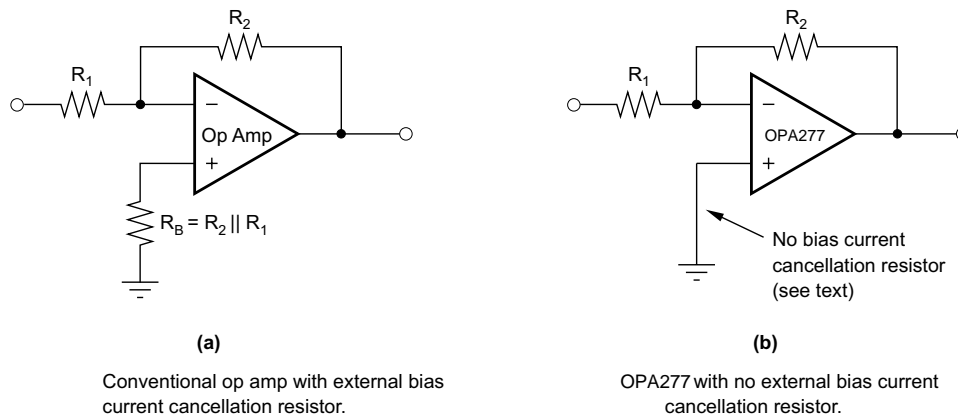


Figure 26. Input Bias Current Cancellation

Feature Description (continued)

7.3.5 EMI Rejection Ratio (EMIRR)

The electromagnetic interference (EMI) rejection ratio, or EMIRR, describes the EMI immunity of operational amplifiers. An adverse effect that is common to many operational amplifiers is a change in the offset voltage as a result of RF signal rectification. An operational amplifier that is more efficient at rejecting this change in offset as a result of EMI has a higher EMIRR and is quantified by a decibel value. Measuring EMIRR can be performed in many ways, but this report provides the EMIRR IN+, which specifically describes the EMIRR performance when the RF signal is applied to the noninverting input pin of the operational amplifier. In general, only the noninverting input is tested for EMIRR for the following three reasons:

1. Operational amplifier input pins are known to be the most sensitive to EMI, and typically rectify RF signals better than the supply or output pins.
2. The noninverting and inverting operational amplifier inputs have symmetrical physical layouts and exhibit nearly matching EMIRR performance.
3. EMIRR is easier to measure on noninverting pins than on other pins because the noninverting input terminal can be isolated on a printed circuit board (PCB). This isolation allows the RF signal to be applied directly to the noninverting input terminal with no complex interactions from other components or connecting PCB traces.

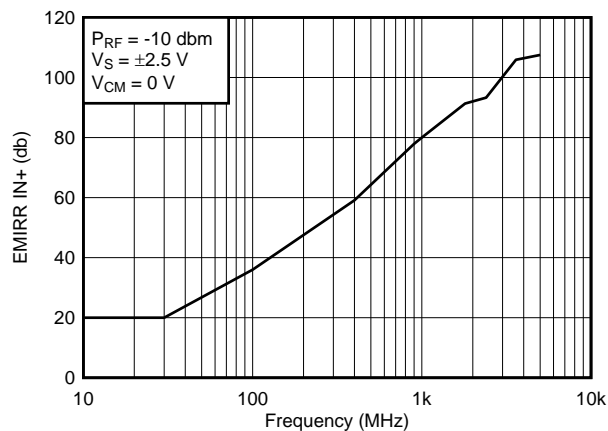


Figure 27. OPA277 EMIRR IN+ vs Frequency

If available, any dual and quad operational amplifier device versions have nearly similar EMIRR IN+ performance. The OPA277 unity-gain bandwidth is 1 MHz. EMIRR performance below this frequency denotes interfering signals that fall within the operational amplifier bandwidth.

Feature Description (continued)

Table 1 shows the EMIRR IN+ values for the OPA277 at particular frequencies commonly encountered in real-world applications. Applications listed in Table 1 may be centered on or operated near the particular frequency shown. This information may be of special interest to designers working with these types of applications, or working in other fields likely to encounter RF interference from broad sources, such as the industrial, scientific, and medical (ISM) radio band.

Table 1. OPA277 EMIRR IN+ for Frequencies of Interest

| FREQUENCY | APPLICATION/ALLOCATION | EMIRR IN+ |
|-----------|--|-----------|
| 400 MHz | Mobile radio, mobile satellite/space operation, weather, radar, UHF | 59.1 dB |
| 900 MHz | GSM, radio com/nav./GPS (to 1.6 GHz), ISM, aeronautical mobile, UHF | 77.9 dB |
| 1.8 GHz | GSM, mobile personal comm. broadband, satellite, L-band | 91.3 dB |
| 2.4 GHz | 802.11b/g/n, Bluetooth™, mobile personal comm., ISM, amateur radio/satellite, S-band | 93.3 dB |
| 3.6 GHz | Radiolocation, aero comm./nav., satellite, mobile, S-band | 105.9 dB |
| 5.0 GHz | 802.11a/n, aero comm./nav., mobile comm., space/satellite operation, C-band | 107.5 dB |

7.3.5.1 EMIRR IN+ Test Configuration

Figure 28 shows the circuit configuration for testing the EMIRR IN+. An RF source is connected to the operational amplifier noninverting input terminal using a transmission line. The operational amplifier is configured in a unity gain buffer topology with the output connected to a low-pass filter (LPF) and a digital multimeter (DMM). Note that a large impedance mismatch at the operational amplifier input causes a voltage reflection; however, this effect is characterized and accounted for when determining the EMIRR IN+. The resulting dc offset voltage is sampled and measured by the multimeter. The LPF isolates the multimeter from residual RF signals that may interfere with multimeter accuracy. Refer to SBOA128 for more details.

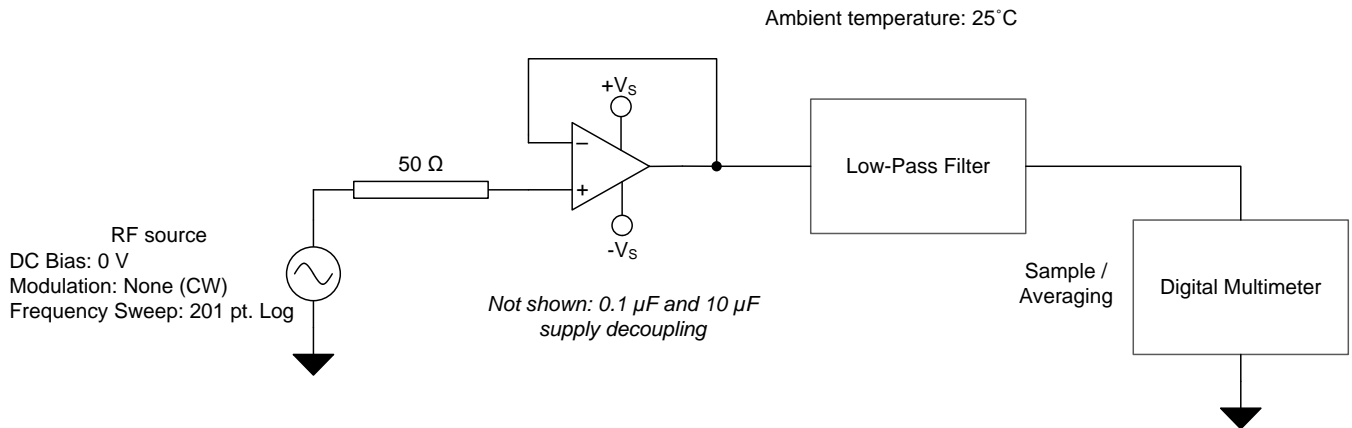


Figure 28. EMIRR IN+ Test Configuration Schematic

7.4 Device Functional Modes

The OPAx277 has a single functional mode and is operational when the power-supply voltage is greater than 4 V (±2 V). The maximum power supply voltage for the OPAx277 is 36 V (±18 V).

PACKAGE

SOP8

The SOP8 package is shown in two views. The top view shows a rectangular package with dimensions B (width) and C (height). The lead width is 'a' and the lead spacing is 'b'. The lead height is 'C1'. The side view shows the lead height 'A', the lead thickness 'A1', the lead width 'Q', and the lead diameter 'D'. A dimension of 0.25 is also indicated for the lead thickness.

| Dimensions In Millimeters | | | | | |
|---------------------------|-------|-------|----------|-----------|-------|
| Symbol : | Min : | Max : | Symbol : | Min : | Max : |
| A | 1.225 | 1.570 | D | 0.400 | 0.950 |
| A1 | 0.100 | 0.250 | Q | 0° | 8° |
| B | 4.800 | 5.100 | a | 0.420 TYP | |
| C | 5.800 | 6.250 | b | 1.270 TYP | |
| C1 | 3.800 | 4.000 | | | |

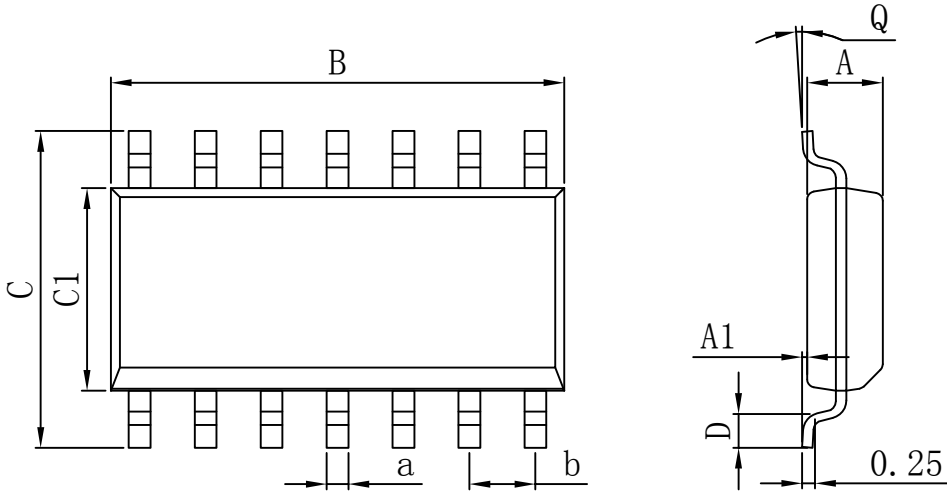
DIP8

The DIP8 package is shown in three views. The top view shows dimensions B (width) and E (height). The lead width is 'a' and the lead spacing is 'b'. The lead height is 'L1'. The side view shows the lead height 'L', the lead width 'D1', and the lead diameter 'D'. The bottom view shows the package width 'A'.

| Dimensions In Millimeters | | | | | |
|---------------------------|-------|-------|----------|-----------|-------|
| Symbol : | Min : | Max : | Symbol : | Min : | Max : |
| A | 6.100 | 6.680 | L1 | 3.000 | 3.600 |
| B | 9.000 | 9.500 | a | 1.524 TYP | |
| D | 8.400 | 9.000 | b | 0.889 TYP | |
| D1 | 7.420 | 7.820 | c | 0.457 TYP | |
| E | 3.100 | 3.550 | d | 2.540 TYP | |
| L | 0.500 | 0.700 | | | |

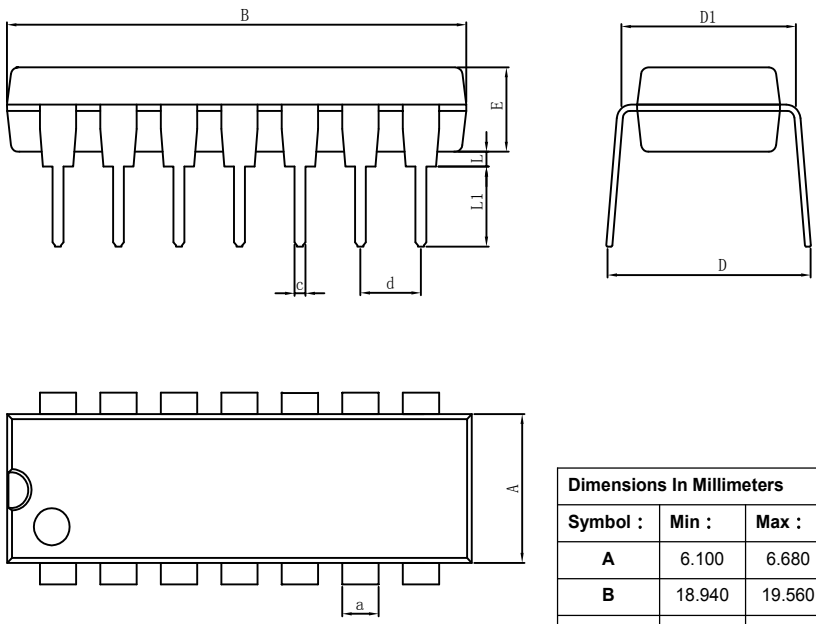
PACKAGE

SOP14



| Dimensions In Millimeters | | | | | |
|---------------------------|-------|-------|----------|-----------|-------|
| Symbol : | Min : | Max : | Symbol : | Min : | Max : |
| A | 1.225 | 1.570 | D | 0.400 | 0.950 |
| A1 | 0.100 | 0.250 | Q | 0° | 8° |
| B | 8.500 | 9.000 | a | 0.420 TYP | |
| C | 5.800 | 6.250 | b | 1.270 TYP | |
| C1 | 3.800 | 4.000 | | | |

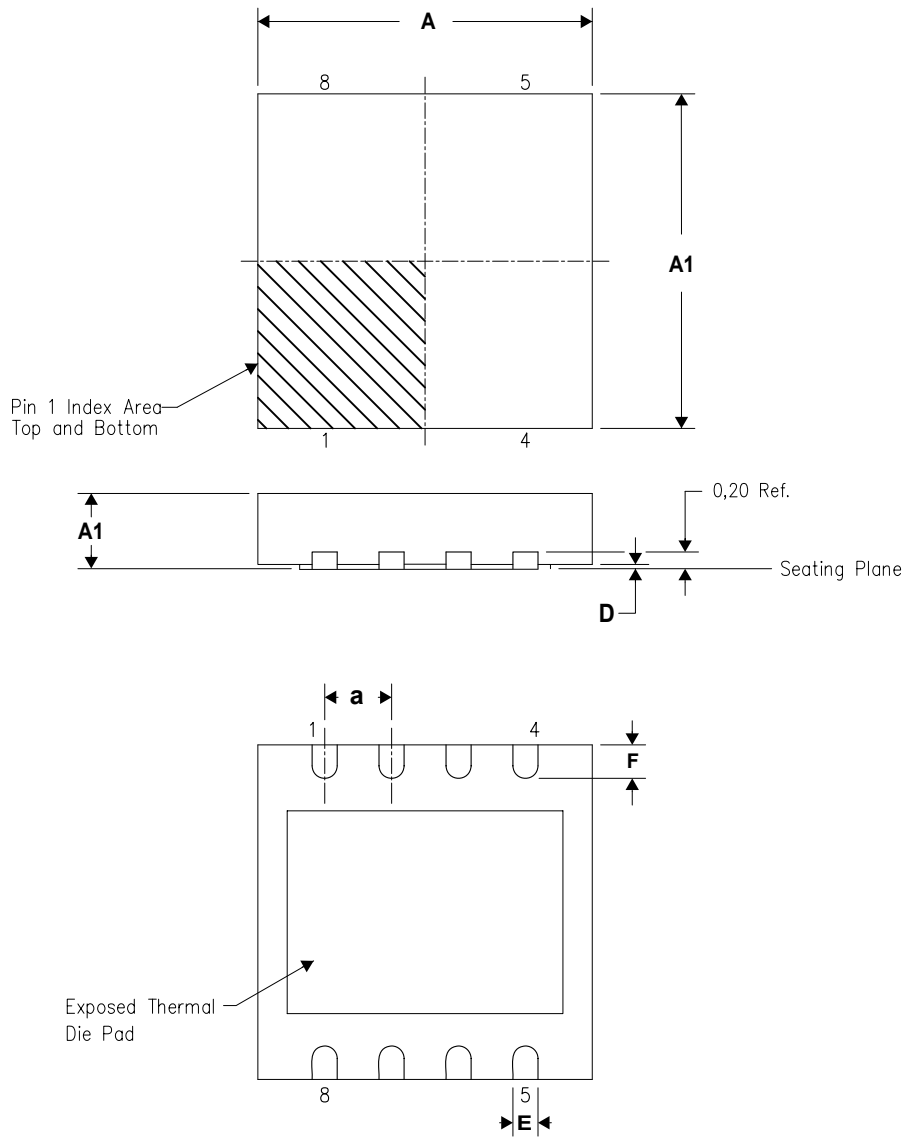
DIP14



| Dimensions In Millimeters | | | | | |
|---------------------------|--------|--------|----------|-----------|-------|
| Symbol : | Min : | Max : | Symbol : | Min : | Max : |
| A | 6.100 | 6.680 | L | 0.500 | 0.800 |
| B | 18.940 | 19.560 | L1 | 3.000 | 3.600 |
| D | 8.200 | 9.200 | a | 1.524 TYP | |
| D1 | 7.42 | 7.820 | c | 0.457 TYP | |
| E | 3.100 | 3.550 | d | 2.540 TYP | |

PACKAGE

DFN-8



| Dimensions In Millimeters | | | | | |
|---------------------------|-------|-------|----------|----------|-------|
| Symbol : | Min : | Max : | Symbol : | Min : | Max : |
| A | 3.900 | 4.100 | E | 0.230 | 0.380 |
| A1 | 3.900 | 4.100 | F | 0.300 | 0.500 |
| B | 0.800 | 1.000 | a | 0.80 TYP | |
| D | 0.000 | 0.050 | | | |

Important statement:

Huaguan Semiconductor Co,Ltd. reserves the right to change the products and services provided without notice. Customers should obtain the latest relevant information before ordering, and verify the timeliness and accuracy of this information.

Customers are responsible for complying with safety standards and taking safety measures when using our products for system design and machine manufacturing to avoid potential risks that may result in personal injury or property damage.

Our products are not licensed for applications in life support, military, aerospace, etc., so we do not bear the consequences of the application of these products in these fields.

Our documentation is only permitted to be copied without any tampering with the content, so we do not accept any responsibility or liability for the altered documents.